

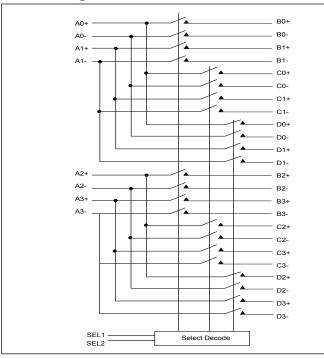


3.3V, PCI Express® 3.0 2-Lane, 3:1 Mux/DeMux Switch, with Power Down Feature

Features

- → 4 Differential Channel, 3:1 Mux/DeMux
- → PCI Express[®] 3.0 Performance, 8.0Gbps
- → Bi-directional operation
- → -3dB Bandwidth: 6.8GHz
- → Low Bit-to-Bit Skew, 10ps max
- → Low Crosstalk: -40dB@4 GHz
- → Low Insertion Loss: -1.4dB@4 GHz (8.0Gbps)
- → Low Return Loss:-15dB@4GHz (8.0Gbps)
- → Low Off Isolation:-19dB @4GHz (8Gbps)
- → ESD:1.5KV HBM
- → Power Down option
- → Supply Voltage 3.3V
- → Packaging (Pb-free & Green):
 - 42-contact, TQFN (ZH42)

Block Diagram



Truth Table

SEL1	SEL2	Function
0	0	Power down all switch hi-z
0	1	A→B
1	0	A→C
1	1	A→D

Description

The PI3PCIE3413A is an 12 to 4 differential channel multiplexer/ demultiplexer switch. This solution can switch 2 full PCI Express* 3.0, lanes to one of three locations. Using a unique design technique, Diodes Incorporated has been able to minimize the impedance of the switch such that the attenuation observed through the switch is mininal. The unique design technique also offers a layout targeted for PCI Express signals, which minimizes the channel to channel skew as well as channel to channel crosstalk as required by the PCI Express specification.

Application

Routing of PCI Express 3.0, signals with low signal attenuation.

Pin Description (Top-side view)

=	•				,
		GND SEL1	SEL2 GND		
		1:11	00		
			40 39		
$V_{_{DD}}$	1111		10 00	38 🛄	V _{DD}
A0+	2		1	37 🛄	B0+
A0-	3			36 🗔	В0-
D0+	4			35 🛄	C0+
D0-	5			34 🛄	C0-
A1+	6		1	33 🗔	B1+
A1-	7			32	B1-
D1+	8			31	C1+
				30	
D1-	9		-	30	C1-
A2+	10	1		29 🛄	B2+
A2-	11			28 🗔	B2-
D2+	12			27 🗔	C2+
D2-	<u></u> : 13			26	C2-
A3+	14			25	B3+
A3-	15			24	B3-
D3+	16			23	C3+
D3-	17	¦	ني	22	C3-
20	[20 21		
	-				
		GND 	GND C		
		0 -			





Pin Description

Pin #	Pin Name	I/O	Description		
2	A0+	I/O	Signal I/O, Channel 0, Port A		
3	A0-				
6	A1+	I/O	ignal I/O. Channel I. Dort A		
7	A1-	1/0	Signal I/O, Channel 1, Port A		
10	A2+	I/O	Signal I/O, Channel 2, Port A		
11	A2-	1/0			
14	A3+	I/O	Signal I/O, Channel 3, Port A		
15	A3-	1/0			
37	B0+	I/O	Signal I/O, Channel 0, Port B		
36	B0-	1/0	Signal 1/0, Channel 0, Port B		
33	B1+	I/O	Signal I/O, Channel 1, Port B		
32	B1-	1/0			
29	B2+	I/O	Signal I/O. Channel 2. Dont P.		
28	B2-	1/0	Signal I/O, Channel 2, Port B		
25	B3+	1/0	Signal I/O. Channel 2. Don't P.		
24	В3-	I/O	Signal I/O, Channel 3, Port B		
35	C0+	I/O	Signal I/O, Channel 0, Port C		
34	C0-	1/0			
31	C1+	I/O	Signal I/O, Channel 1, Port C		
30	C1-	1/0	Signal 1/0, Channel 1, Port C		
27	C2+	I/O	Signal I/O, Channel 2, Port C		
26	C2-	1/0	Signal 1/0, Channel 2, Port C		
23	C3+	1/0	Simulation Channel 2 Bart C		
22	C3-	I/O	Signal I/O, Channel 3, Port C		
4	D0+		Simulation Channel & Bart D		
5	D0-	I/O	Signal I/O, Channel 0, Port D		
8	D1+				
9	D1-	I/O	Signal I/O, Channel 1, Port D		
12	D2+	1/0	Signal I/O Channel 2 Dont D		
13	D2-	I/O	Signal I/O, Channel 2, Port D		
16	D3+		Sand I/O Channel 2 Bart D		
17	D3-	I/O Signal I/O, Channel 3, Port D			
40, 41	SEL2, SEL1	I	Operation mode Select. Please see Truth Table on Page 1		
1, 19, 20, 38	V _{DD}	Pwr	3.3V ±10% Positive Supply Voltage		
18, 21, 39, 42, Center Pad	GND	Pwr	Power ground		





Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	65°C to +150°C
Supply Voltage to Ground Potential	0.5V to +3.7V
Channel DC Input Voltage	–0.5V to 1.5V
DC Output Current	120mA
Power Dissipation	0.5W
SEL DC Input Voltage	–0.5V to 3.7V
Junction Temperature	125°C

Note: Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Electrical Characteristics

Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{DD}	3.3V Power Supply		3.0	3.3	3.6	V
I _{DD}	Total current from V _{DD} 3.3V supply	SEL1,2 = 01, 10 or 11		0.15	1	mA
I _{DDQ}	Standby I _{DD}	SEL1,2 = 00		0.1		
T _{CASE}	Case temperature range for operation within spec.		-40		85	Celsius

DC Electrical Characteristics for Switching over Operating Range

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽¹⁾	Max.	Units
V _{IH} - SEL	Input HIGH Voltage, SEL Input		2		3.6	
V _{IL} - SEL	Input LOW Voltage, SEL Input		0		0.8	V
V _{IK}	Clamp Diode Voltage	V_{DD} = Max., I_{IN} = -18mA		-0.7	-1.2	
IIH	Input HIGH Current, SEL	V_{DD} = Max., V_{IN} = V_{DD}			±5	
IIL	Input LOW Current, SEL	$V_{DD} = Max., V_{IN} = 0V$			±5	μΑ
IIH	Input HIGH Current, A _X , B _X , C _X , D _x	V_{DD} = Max., V_{IN} = 1.5V	-10		+10	
IIL	Input LOW Current, A _X , B _X , C _X , D _x	$V_{DD} = Max., V_{IN} = 0V$	-10		+10	μA
IOZH	HighZ HIGH Current, B_X , C_X , D_x	V_{DD} = Max., V_{IN} = 1.5V	-10		+10	μΑ
I _{OZL}	HighZ LOW Current, B _X , C _X , D _x	$V_{DD} = Max., V_{IN} = 0V$	-10		+10	μΑ

Note:

1. Typical values are at V_{DD} = 3.3V, T_A = 25°C ambient and maximum loading.

Switching Characteristics

Parameters	Description	Test Conditions	Min.	Тур.	Max.	Units
tpZH, tpZL	Line Enable Time - SEL to A_N , B_N , C_N , D_N		0.5	41	55	
tpHZ, tPLZ	Line Disable Time - SEL to A _N , B _N , C _N , D _N 0.5525		ns			
t _{b-b}	Bit-to-bit skew within the same differential pair			5	10	ps

Notes:

1. Guaranteed by design. Typical values are at V^{DD} = 3.3V , T^A = 25°C ambient and maximum loading.



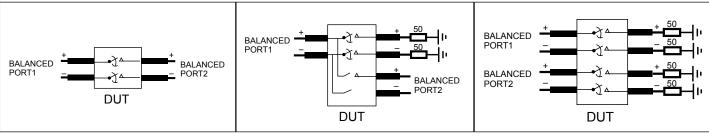


Dynamic Electrical Characteristics

Parameter	Description	Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Units
		f= 50MHz - 1.25GHz	-0.8	-0.6		
ווחח	Differential Insertion Loss	f= 1.25GHz - 2.5GHz	-1.2	-1.0		dB
DDIL	$(V_{IN} = -10 dBm, DC = 0V)$	f= 2.5GHz - 4.0GHz	-1.7	-1.4		uв
		f= 5.0GHz	-2.3	-1.9		
		f= 50MHz - 1.25GHz		-24	-21	
ווחס	Differential Return Loss	f= 1.25GHz - 2.5GHz		-21	-18.5	σι
DDIL _{RL}		f= 2.5GHz - 4.0GHz		-15	-13.4	dB
		f= 5.0GHz		-11	-9.8	
	Differential Off Isolation	f= 50MHz - 1.25GHz		-34.8	-27.8	
DD 11		f= 1.25GHz - 2.5GHz		-25.2	-20.2	dB
DDIL _{OFF}		f= 2.5GHz - 4.0GHz		-19.5	-15.6	uв
		f= 5.0GHz		-18.5	-14.8	
		f= 50MHz - 1.25GHz		-48.5	-38.8	
DDMEVT		f= 1.25GHz - 2.5GHz		-43.4	-34.7	аĿ
DDNEXT	Near End Crosstalk	f= 2.5GHz - 4.0GHz		-42.7	-34.2	dB
		f= 5.0GHz		-42.7	-34.2	
BW	-3dB Bandwidth			6.8		GHz

Notes:

1. Guaranteed by design. Typical values are at V_{DD} = 3.3V , T_A = 25°C ambient and maximum loading.



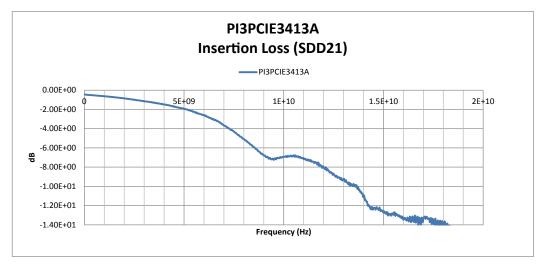
Diff. Insertion Loss and Return Test Circuit

Diff. Off Isolation Test Circuit

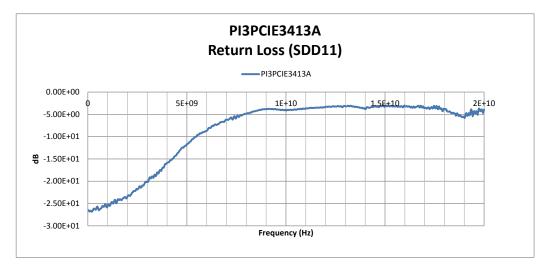
Diff. Near End Xtalk Test Circuit







Differential Insertion Loss



Differential Return Loss







Differential Off Isolation

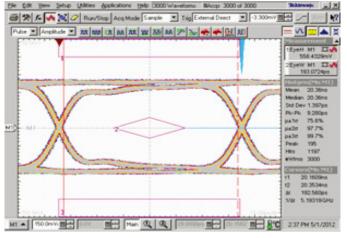


Differential Crosstalk

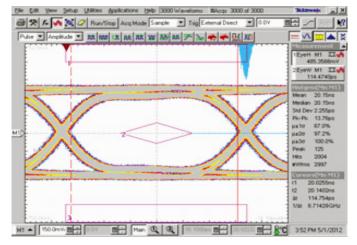


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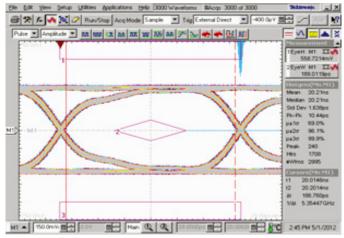
PI3PCIE3413A



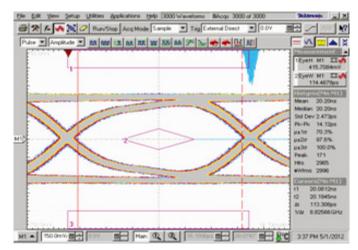
5.0 Gbps RX signal eye without PI3PCIE3413A



8.0 Gbps RX signal eye without PI3PCIE3413A



5.0 Gbps RX signal eye with PI3PCIE3413A



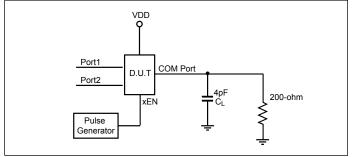
8.0 Gbps RX signal eye with PI3PCIE3413A



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Test Circuit for Electrical Characteristics⁽¹⁻⁵⁾



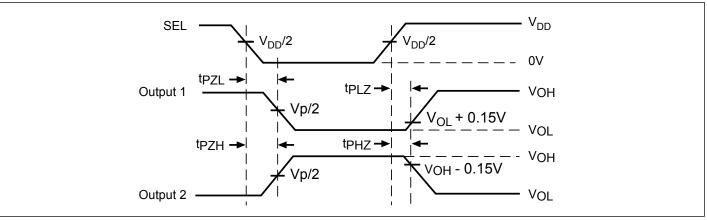
Notes:

- 1. C_L = Load capacitance: includes jig and probe capacitance.
- 2. R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator
- 3. Output 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
- output 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- 4. All input impulses are supplied by generators having the following characteristics: $PRR \le MHz$, $Z_O = 50\Omega$, $t_R \le 2.5ns$, $t_F \le 2.5ns$.
- 5. The outputs are measured one at a time with one transition per measurement.

Switch Positions

Test	Switch
t _{PLZ} , t _{PZL}	3.0V
t _{PHZ} , t _{PZH}	GND
Prop Delay	Open

Switching Waveforms

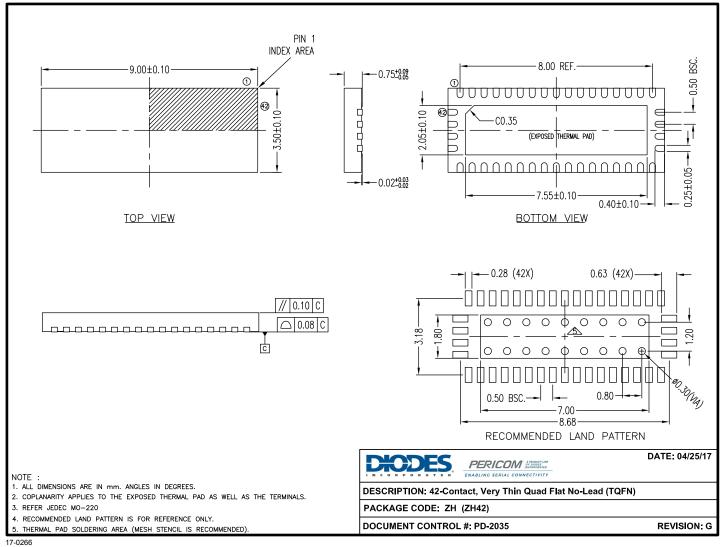


Voltage Waveforms Enable and Disable Times





Packaging Information: 42-contact (TQFN)



For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Package Code	Package Description
PI3PCIE3413AZHEX	ZH	42-contact, Thin Fine Pitch Quad Flat No-Lead (TQFN)

Notes:

· Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/

• E = Pb-free and Green

• X suffix = Tape/Reel





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